

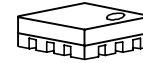
PDC Dual Band MIXER GaAs MMIC

■GENERAL DESCRIPTION

The NJG1560PB1 is a mixer GaAs MMIC includes local amplifier targeted to dual band (800MHz, 1.5GHz) application. The band switching between 800MHz and 1500MHz is made by 1bit control signal by using inverter circuit included in this IC.

The ultra small and thin FFP12-B1 is applied.

■PACKAGE OUTLINE



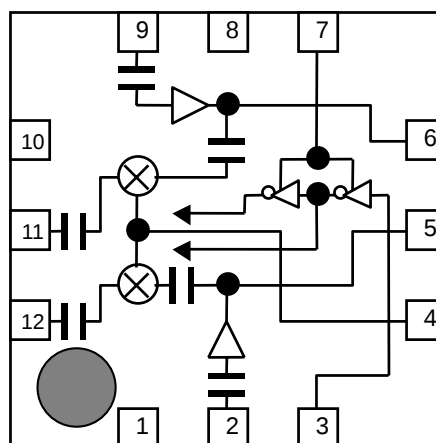
NJG1560PB1

■FEATURES

- | | | |
|-----------------------------|---|--|
| ●Low voltage operation | +2.8V typ. | |
| ●Low current consumption | 5.9mA typ. | |
| ●Low Inverter current | 100uA typ. | |
| ●High conversion gain | 11dB typ. | @V _{CTL} =0V, f _{RF1} =820MHz |
| | 11dB typ. | @V _{CTL} =2.4V, f _{RF2} =1489MHz |
| ●High input IP3 | +3dBm typ. | @V _{CTL} =0V, f _{RF1} =820MHz |
| | +3dBm typ. | @V _{CTL} =2.4V, f _{RF2} =1489MHz |
| ●Low noise figure | 5.5dB typ. | @V _{CTL} =0V, f _{RF1} =820MHz |
| | 5.0dB typ. | @V _{CTL} =2.4V, f _{RF2} =1489MHz |
| ●Ultra small & thin package | FFP12-B1 (Package size: 2.0mmx2.0mmx0.85mm) | |

■PIN CONFIGURATION

(Top View)



Pin Connection

1. GND
2. LOIN1 (800MHz)
3. VCTL
4. IFOUT
5. VLO1 (800MHz)
6. VLO2 (1.5GHz)
7. VINV
8. GND
9. LOIN2 (1.5GHz)
10. GND
11. RFIN2 (1.5GHz)
12. RFIN1 (800MHz)

Note: The specifications and description listed in this catalog are subject to change without prior notice.

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■ABSOLUTE MAXIMUM RATINGS

(T_a=25°C, Z_s=Z_l=50Ω)

PARAMETERS	SYMBOL	CONDITIONS	RATINGS	UNITS
Operating voltage	V _{DD}	IFOUT, VLO 1, VLO2, VINV ports	5.0	V
Control voltage	V _{CTL}	VCTL port	V _{INV}	V
Input power	P _{in}	RFIN1, RFIN2, LOIN1, LOIN2 ports	+10	dBm
Power dissipation	P _D		300	mW
Operating temperature	T _{opr}		-40~+85	°C
Storage temperature	T _{stg}		-55~+125	°C

■ELECTRICAL CHARACTERISTICS 1 (DC)

GENERAL CONDITIONS: T_a=25°C, V_{MIX}=V_{LO1}=V_{LO2}=V_{INV}=2.8V

PARAMETERS	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
Mixer supply voltage	V _{MIX}	IFOUT port	2.5	2.8	4.5	V
Local Amplifier supply voltage 1	V _{LO1}	VLO1 ports	2.5	2.8	4.5	V
Local Amplifier supply voltage 2	V _{LO2}	VLO2 ports	2.5	2.8	4.5	V
Inverter supply voltage	V _{INV}	VINV port	2.5	2.8	4.5	V
Mixer current	I _{MIX}	IFOUT port, P _{RF} =P _{LO} =OFF, V _{CTL} =0V or 2.4V	-	4.9	6.1	mA
Local Amplifier current1	I _{LO1}	VLO1 port, P _{RF} =P _{LO} =OFF, V _{CTL} =0V	-	1.0	1.2	mA
Local Amplifier current2	I _{LO2}	VLO2port, P _{RF} =P _{LO} =OFF, V _{CTL} =2.4V	-	1.0	1.2	mA
Inverter current	I _{INV}	VINV port	-	100	150	uA
Control voltage (LOW)	V _{CTL(L)}	VCTL port	0	0	0.8	V
Control voltage (HIGH)	V _{CTL(H)}	VCTL port	2.0	2.4	V _{INV}	V
Control current	I _{CTL}	VCTL port, V _{CTL} =2.4V	-	20	40	uA

■ELECTRICAL CHARACTERISTICS 2 (800MHz RF)

GENERAL CONDITIONS: $T_a=+25^{\circ}\text{C}$, $V_{\text{MIX}}=V_{\text{LO1}}=V_{\text{INV}}=2.8\text{V}$, $V_{\text{CTL}}=0\text{V}$, $f_{\text{RF1}}=820\text{MHz}$,
 $P_{\text{RF1}}=-30\text{dBm}$, $f_{\text{LO1}}=689.95\text{MHz}$, $P_{\text{LO1}}=-15\text{dBm}$,
 $f_{\text{IF}}=130.05\text{MHz}$, $Z_s=Z_l=50\Omega$, with application circuit

PARAMETERS	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
Operating frequency	freq	RFIN1 port	810	820	885	MHz
Conversion gain	Gc		10.0	11.0	12.0	dB
Noise figure	NF	SSB NF	-	5.5	6.5	dB
Input 3rd order intercept point	IIP3	2 tone offset frequency=100kHz	0	+3.0	-	dBm
Pout at 1dB gain compression point	$P_{-1\text{dB(IN)}}$		-11.0	-9.0	-	dBm
RF IN1 port VSWR	VSWR_{RF}		-	1.5	2.0	
LOCAL IN1 port VSWR	VSWR_{LO}		-	1.5	2.0	
IF OUT port VSWR	VSWR_{IF}		-	1.5	2.0	

■ELECTRICAL CHARACTERISTICS 3 (1.5GHz RF)

GENERAL CONDITIONS: $T_a=+25^{\circ}\text{C}$, $V_{\text{MIX}}=V_{\text{LO2}}=V_{\text{INV}}=2.8\text{V}$, $V_{\text{CTL}}=2.4\text{V}$, $f_{\text{RF2}}=1489\text{MHz}$,
 $P_{\text{RF2}}=-30\text{dBm}$, $f_{\text{LO2}}=1358.95\text{MHz}$, $P_{\text{LO2}}=-15\text{dBm}$,
 $f_{\text{IF}}=130.05\text{MHz}$, $Z_s=Z_l=50\Omega$, with application circuit

PARAMETERS	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
Operating frequency	freq	RFIN2 port	1477	1489	1501	MHz
Conversion gain	Gc		10.0	11.0	12.0	dB
Noise figure	NF	SSB NF	-	5.0	6.0	dB
Input 3rd order intercept point	IIP3	2 tone offset frequency=100kHz	0	+3.0	-	dBm
Pout at 1dB gain compression point	$P_{-1\text{dB(IN)}}$		-11.0	-9.0	-	dBm
RF IN2 port VSWR	VSWR_{RF}		-	1.5	2.0	
LOCAL IN2 port VSWR	VSWR_{LO}		-	1.5	2.0	
IF OUT port VSWR	VSWR_{IF}			1.5	2.0	

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■ TERMINAL INFORMATION

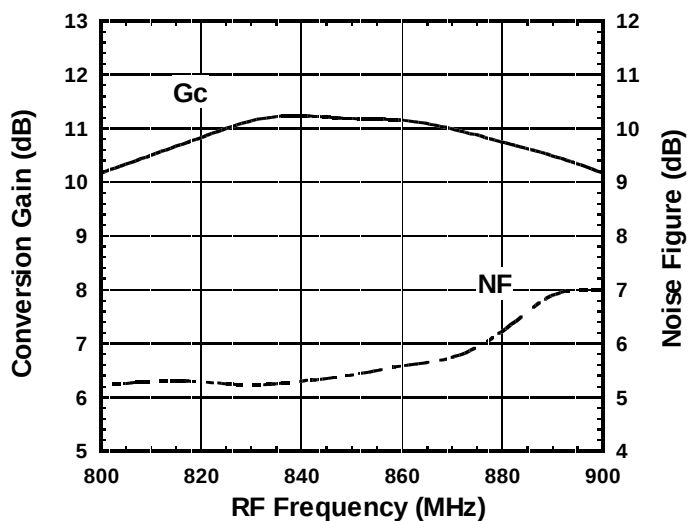
Pin	Symbol	Description
1	GND	Ground terminal(0V).
2	LOIN1	Local power input terminal of 800MHz band local amplifier. External matching circuit is required.
3	VCTL	Control voltage input terminal. This terminal is set to 800MHz band or 1.5GHz band to select.
4	IFOUT	IF signal output terminal for mixer external matching circuit is required. Please connect mixer power supply through choke inductor (L7) as shown in test circuit.
5	VLO1	800MHz band local amplifier supply terminal. Please place L6 close to this terminal as shown in test circuit.
6	VLO2	1.5GHz band local amplifier supply terminal. Please place L5 close to this terminal as shown in test circuit.
7	VINV	Power supply terminal of the inverter circuit.
8	GND	Ground terminal(0V).
9	LOIN2	Local power input terminal of 1.5GHz local amplifier. External matching circuit is required.
10	GND	Ground terminal(0V).
11	RFIN2	RF input terminal of 1.5GHz band mixer. External matching circuit is required.
12	RFIN1	RF input terminal of 800MHz band mixer. External matching circuit is required.

NOTE:

- 1) Ground terminal (1, 8, 10pin) should be connected to ground plane by multiple via holes for good grounding.

TYPICAL CHARACTERISTICS (800MHz Band)

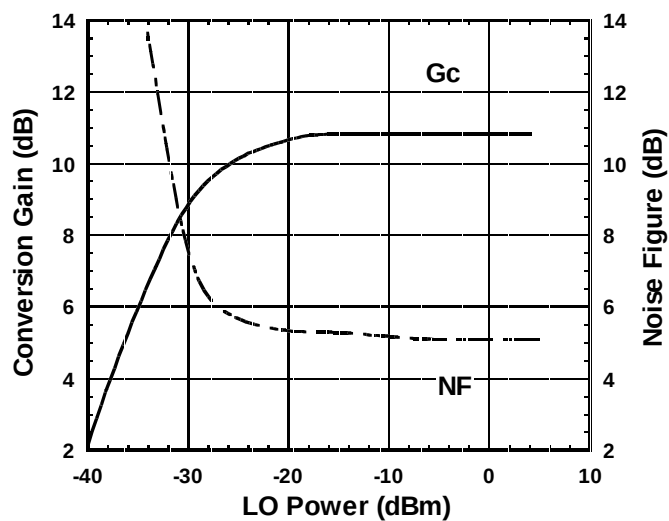
Gc , NF vs. RF Frequency



Condition

$f_{IF}=130.05\text{MHz}$
 $f_{RF}=800\sim 900\text{MHz}$, $P_{RF}=-30\text{dBm}$
 $f_{LO}=669.95\sim 769.95\text{MHz}$, $P_{LO}=-15\text{dBm}$
 $V_{MIX}=V_{LO}=V_{INV}=2.8\text{V}$
 $V_{CTL}=0\text{V}$

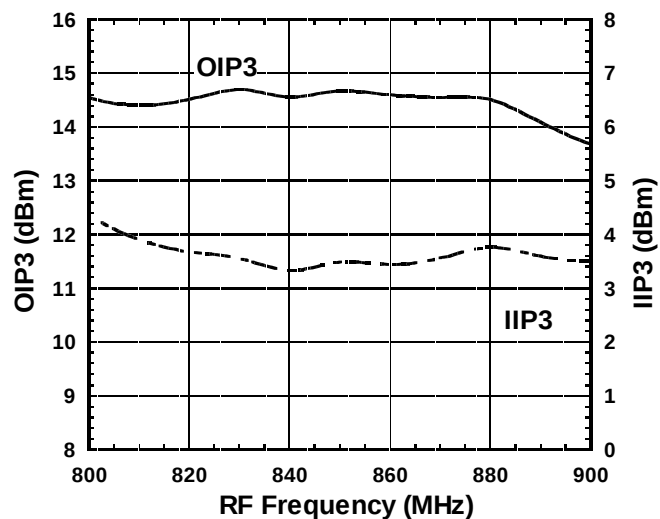
Gc, NF vs. LO Power



Condition

$f_{IF}=130.05\text{MHz}$
 $f_{RF}=820\text{MHz}$, $P_{RF}=-30\text{dBm}$
 $f_{LO}=689.95\text{MHz}$
 $V_{MIX}=V_{LO}=V_{INV}=2.8\text{V}$
 $V_{CTL}=0\text{V}$

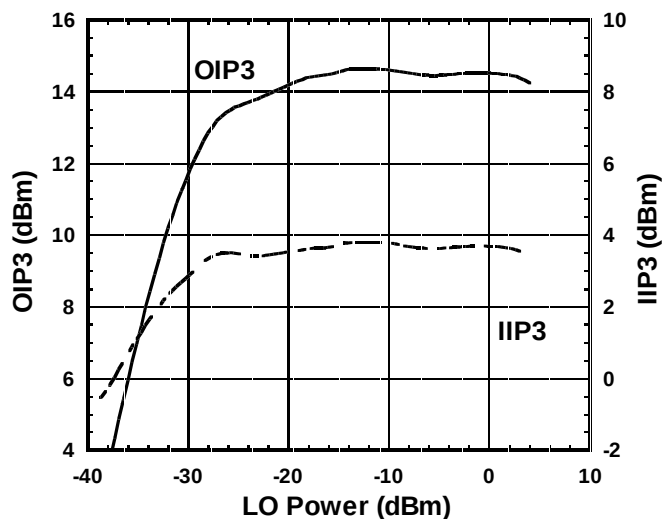
OIP3 , IIP3 vs. RF Frequency



Condition

$f_{IF}=130.05\text{MHz}$
 $f_{RF1}=800\sim 900\text{MHz}$
 $f_{RF2}=f_{RF1}+100\text{kHz}$, $P_{RF}=-30\text{dBm}$
 $f_{LO}=669.95\sim 769.95\text{MHz}$, $P_{LO}=-15\text{dBm}$
 $V_{MIX}=V_{LO}=V_{INV}=2.8\text{V}$
 $V_{CTL}=0\text{V}$

OIP3, IIP3 vs. LO Power



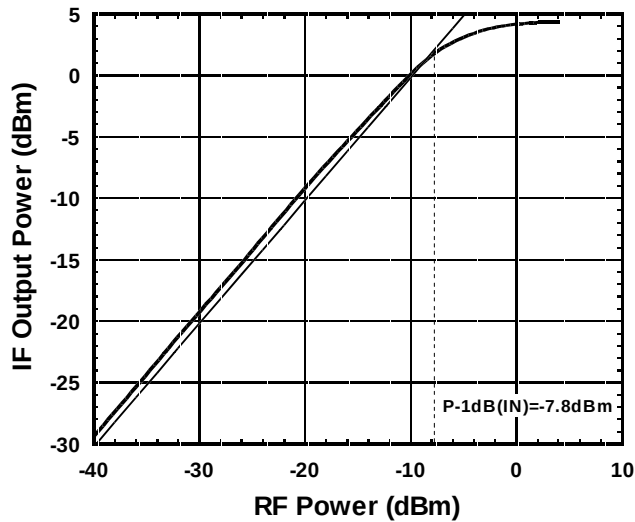
Condition

$f_{IF}=130.05\text{MHz}$
 $f_{RF}=820.0+820.1\text{MHz}$,
 $P_{RF}=-30\text{dBm}$
 $f_{LO}=689.95\text{MHz}$
 $V_{MIX}=V_{LO}=V_{INV}=2.8\text{V}$
 $V_{CTL}=0\text{V}$

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■ TYPICAL CHARACTERISTICS (800MHz Band)

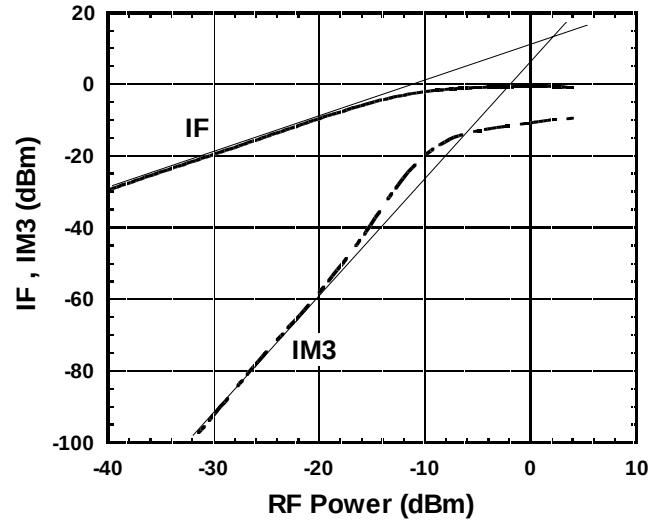
IF Output Power vs. RF Power



Condition

$f_{IF}=130.05\text{MHz}$
 $f_{RF}=820\text{MHz}$
 $f_{LO}=689.95\text{MHz}$, $P_{LO}=-15\text{dBm}$
 $V_{MIX}=V_{LO}=V_{INV}=2.8\text{V}$
 $V_{CTL}=0\text{V}$

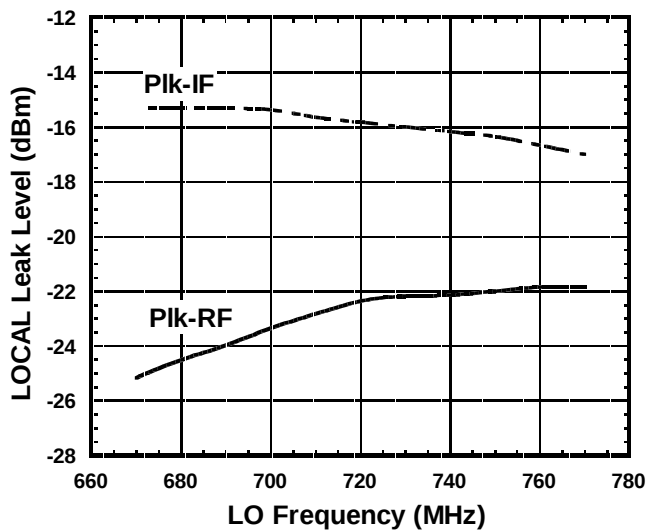
IF, IM3 vs. RF Power



Condition

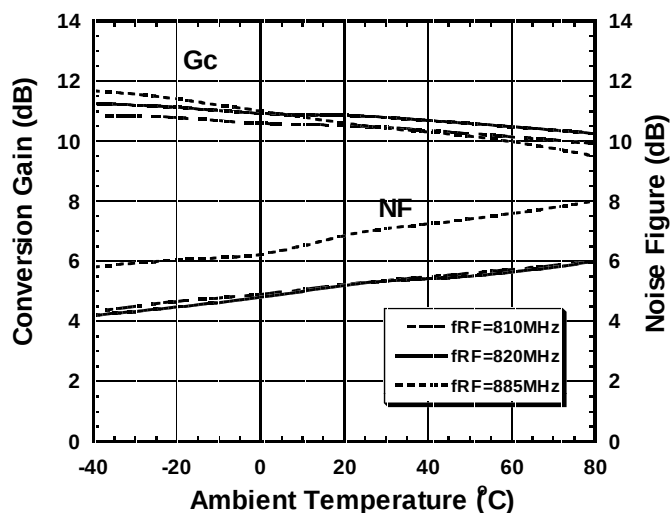
$f_{IF}=130.05\text{MHz}$
 $f_{RF}=820.0+820.1\text{MHz}$
 $f_{LO}=689.95\text{MHz}$, $P_{LO}=-15\text{dBm}$
 $V_{MIX}=V_{LO}=V_{INV}=2.8\text{V}$
 $V_{CTL}=0\text{V}$

LOCAL Leak Level vs. LO Frequency



■ TYPICAL CHARACTERISTICS (800MHz Band)

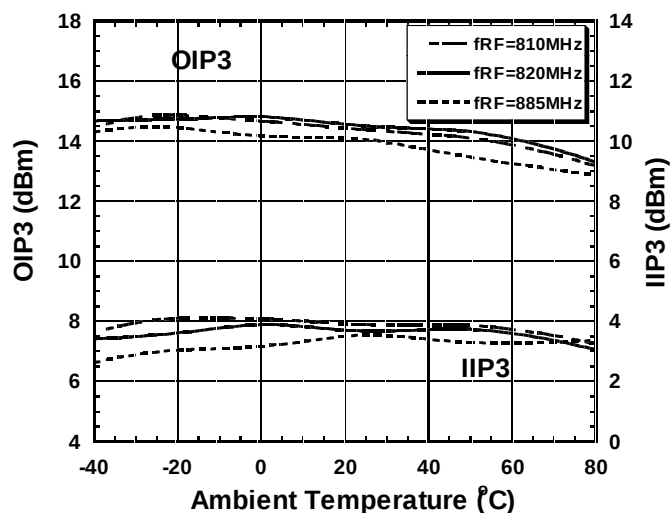
Gc, NF vs. Ambient Temperature



Condition

f_{IF}=130.05MHz
f_{RF}=810~885MHz, P_{RF}=-30dBm
f_{LO}=679.95~754.95MHz, P_{LO}=-15dBm
V_{MIX}=V_{LO}=V_{INV}=2.8V
V_{CTL}=0V

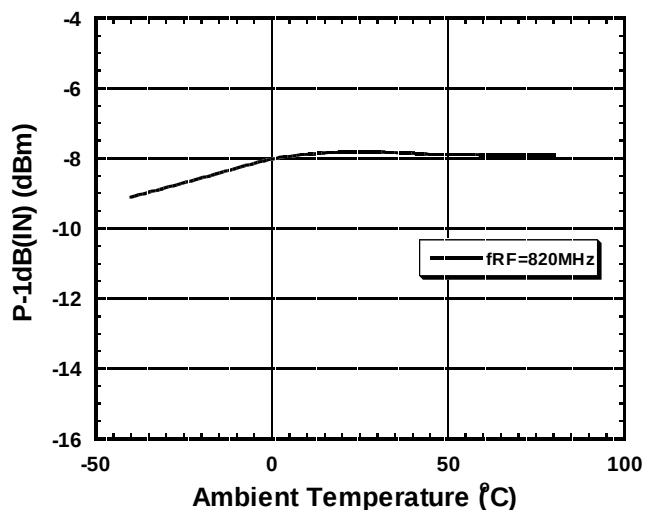
OIP3, IIP3 vs. Ambient Temperature



Condition

f_{IF}=130.05MHz
f_{RF1}=810~885MHz,
f_{RF2}=f_{RF1}+100kHz, P_{RF}=-30dBm
f_{LO}=679.95~754.95MHz, P_{LO}=-15dBm
V_{MIX}=V_{LO}=V_{INV}=2.8V
V_{CTL}=0V

P-1dB(IN) vs. Ambient Temperature



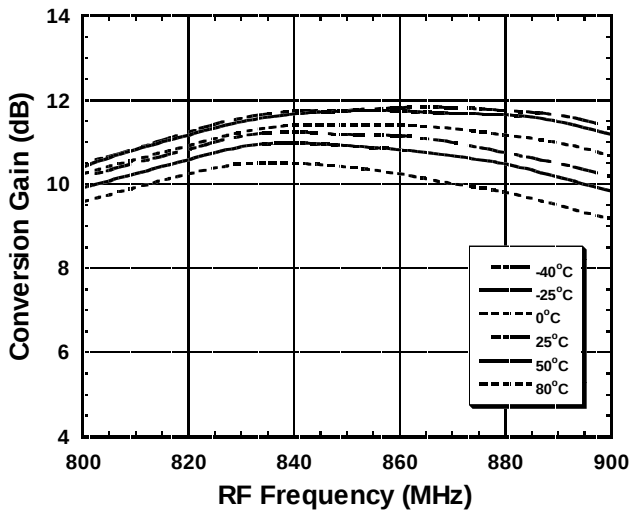
Condition

f_{IF}=130.05MHz
f_{RF}=820MHz
f_{LO}=689.95MHz, P_{LO}=-15dBm
V_{MIX}=V_{LO}=V_{INV}=2.8V
V_{CTL}=0V

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TYPICAL CHARACTERISTICS (800MHz Band)

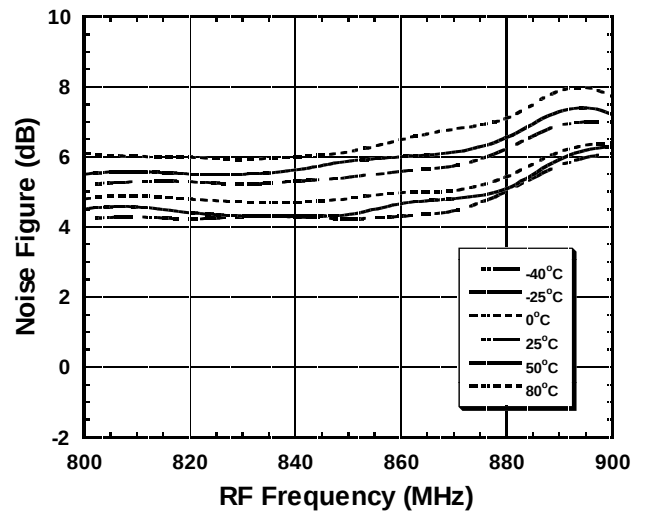
Conversion Gain vs. Frequency



Condition

$f_{IF}=130.05\text{MHz}$
 $f_{RF}=800\sim 900\text{MHz}$, $P_{RF}=-30\text{dBm}$
 $f_{LO}=669.95\sim 769.95\text{MHz}$, $P_{LO}=-15\text{dBm}$
 $V_{MIX}=V_{LO}=V_{INV}=2.8\text{V}$
 $V_{CTL}=0\text{V}$

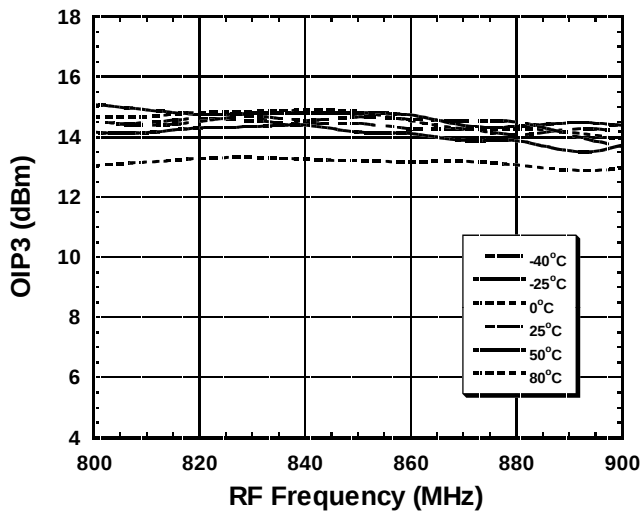
Noise Figure vs. Frequency



Condition

$f_{IF}=130.05\text{MHz}$
 $f_{RF}=800\sim 900\text{MHz}$
 $f_{LO}=669.95\sim 769.95\text{MHz}$, $P_{LO}=-15\text{dBm}$
 $V_{MIX}=V_{LO}=V_{INV}=2.8\text{V}$
 $V_{CTL}=0\text{V}$

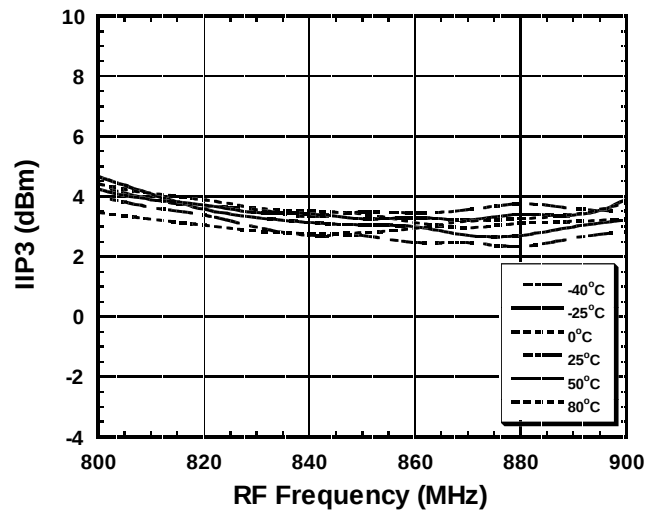
OIP3 vs. Frequency



Condition

$f_{IF}=130.05\text{MHz}$
 $f_{RF1}=800\sim 900\text{MHz}$
 $f_{RF2}=f_{RF1}+100\text{kHz}$, $P_{RF}=-30\text{dBm}$
 $f_{LO}=669.95\sim 769.95\text{MHz}$, $P_{LO}=-15\text{dBm}$
 $V_{MIX}=V_{LO}=V_{INV}=2.8\text{V}$
 $V_{CTL}=0\text{V}$

IIP3 vs. Frequency

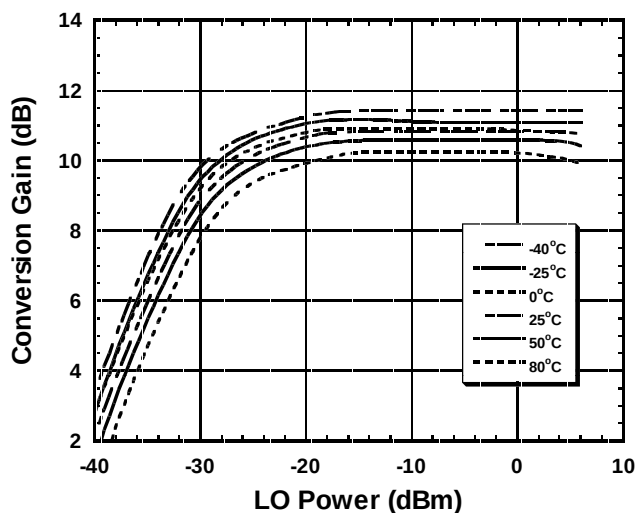


Condition

$f_{IF}=130.05\text{MHz}$
 $f_{RF1}=800\sim 900\text{MHz}$
 $f_{RF2}=f_{RF1}+100\text{kHz}$, $P_{RF}=-30\text{dBm}$
 $f_{LO}=669.95\sim 769.95\text{MHz}$, $P_{LO}=-15\text{dBm}$
 $V_{MIX}=V_{LO}=V_{INV}=2.8\text{V}$
 $V_{CTL}=0\text{V}$

■ TYPICAL CHARACTERISTICS (800MHz Band)

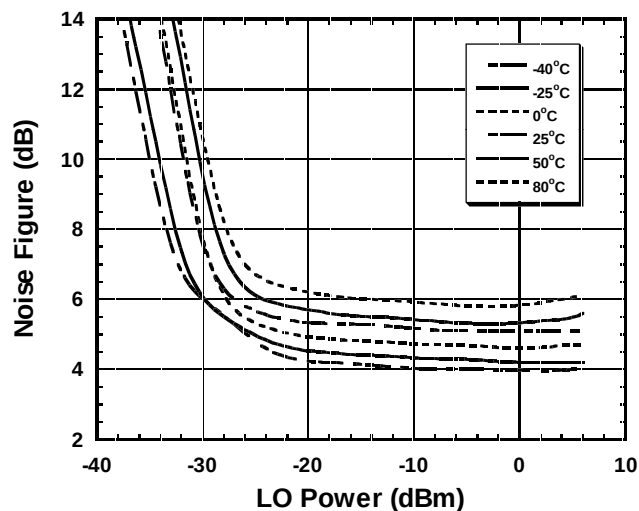
Conversion Gain vs. LO Power



Condition

$f_{IF}=130.05\text{MHz}$
 $f_{RF}=820\text{MHz}$, $P_{RF}=-30\text{dBm}$
 $f_{LO}=689.95\text{MHz}$
 $V_{MIX}=V_{LO}=V_{INV}=2.8\text{V}$
 $V_{CTL}=0\text{V}$

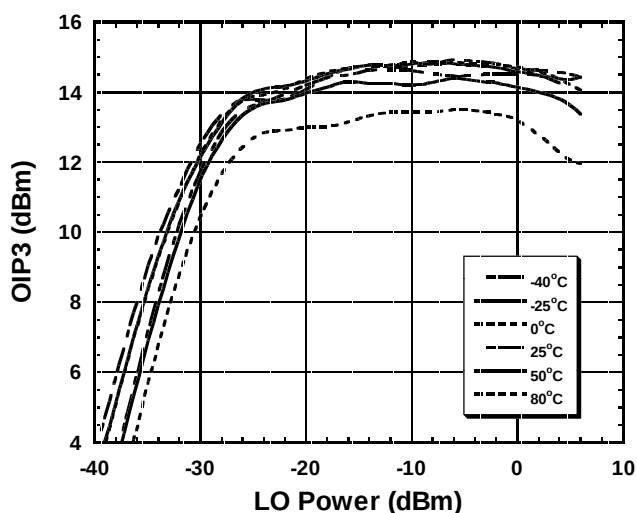
Noise Figure vs. LO Power



Condition

$f_{IF}=130.05\text{MHz}$
 $f_{RF}=820\text{MHz}$
 $f_{LO}=689.95\text{MHz}$
 $V_{MIX}=V_{LO}=V_{INV}=2.8\text{V}$
 $V_{CTL}=0\text{V}$

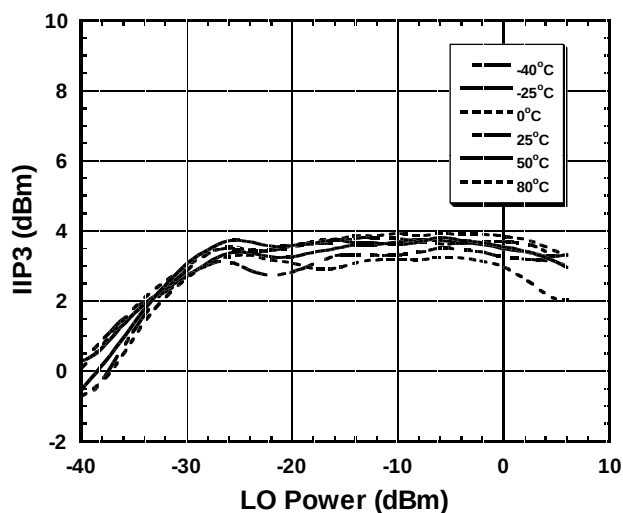
OIP3 vs. LO Power



Condition

$f_{IF}=130.05\text{MHz}$
 $f_{RF}=820.0+820.1\text{MHz}$,
 $P_{RF}=-30\text{dBm}$
 $f_{LO}=689.95\text{MHz}$
 $V_{MIX}=V_{LO}=V_{INV}=2.8\text{V}$
 $V_{CTL}=0\text{V}$

IIP3 vs. LO Power

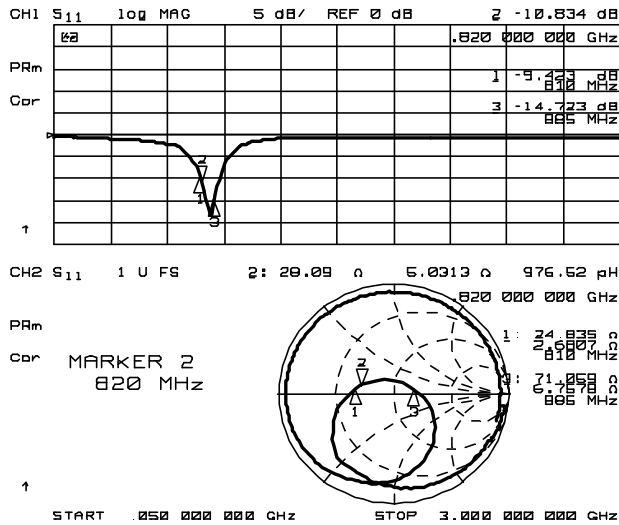


Condition

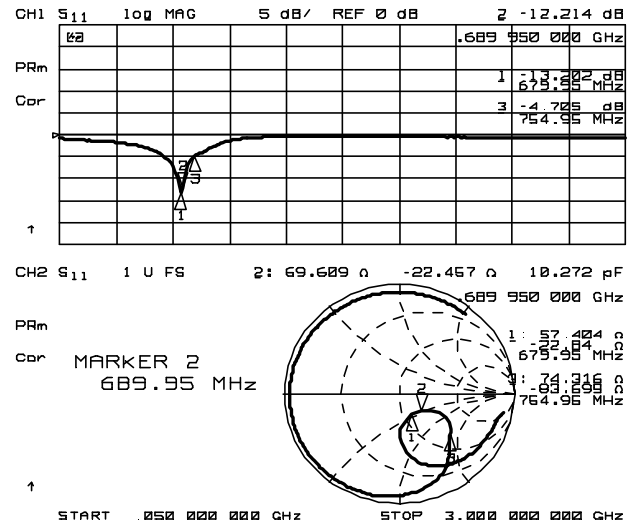
$f_{IF}=130.05\text{MHz}$
 $f_{RF}=820.0+820.1\text{MHz}$,
 $P_{RF}=-30\text{dBm}$
 $f_{LO}=689.95\text{MHz}$
 $V_{MIX}=V_{LO}=V_{INV}=2.8\text{V}$
 $V_{CTL}=0\text{V}$

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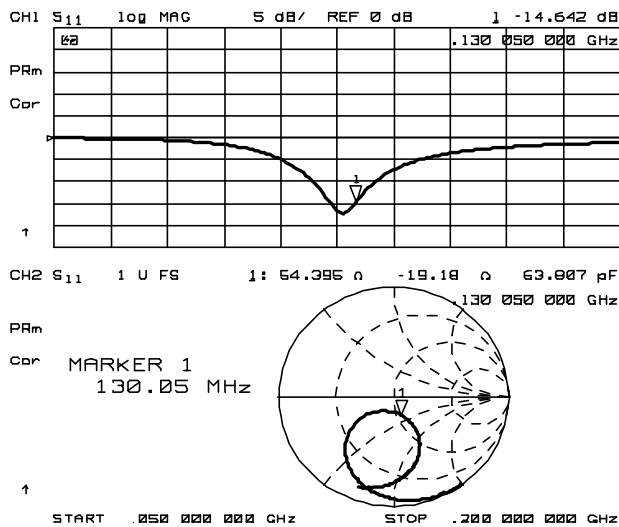
TYPICAL CHARACTERISTICS (800MHz Band)



RF IN1 Port Impedance
(LOCAL IN1 Port, IF OUT Port: 50Ω term.)



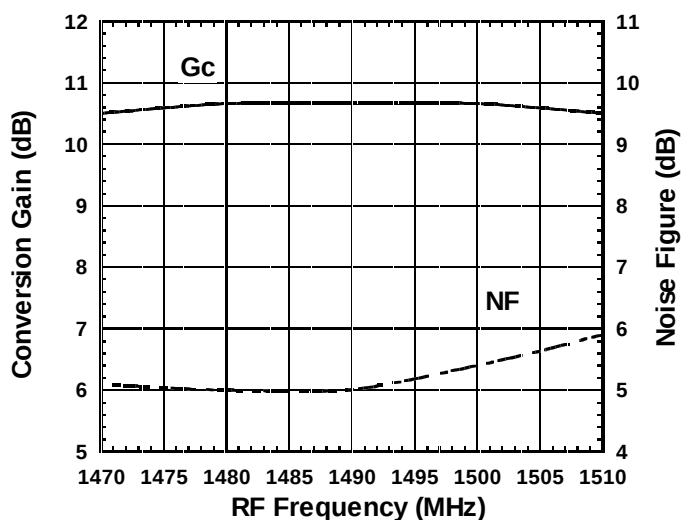
LOCAL IN1 Port Impedance
(RF IN1 Port, IF OUT Port: 50Ω term.)



IF OUT Port Impedance
(RF IN1 Port, LOCAL IN1 Port: 50Ω term.)

■ TYPICAL CHARACTERISTICS (1.5GHz Band)

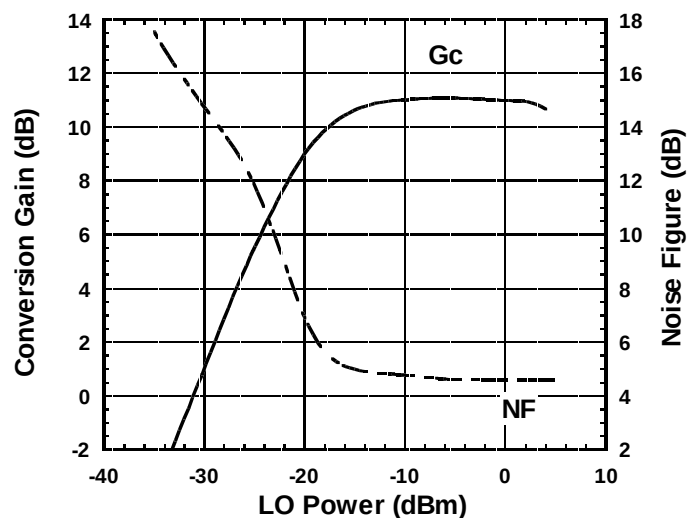
Gc , NF vs. RF Frequency



Condition

$f_{IF}=130.05\text{MHz}$
 $f_{RF}=1470\sim 1510\text{MHz}$, $P_{RF}=-30\text{dBm}$
 $f_{LO}=1339.95\sim 1379.95\text{MHz}$, $P_{LO}=-15\text{dBm}$
 $V_{MIX}=V_{LO}=V_{INV}=2.8\text{V}$
 $V_{CTL}=2.4\text{V}$

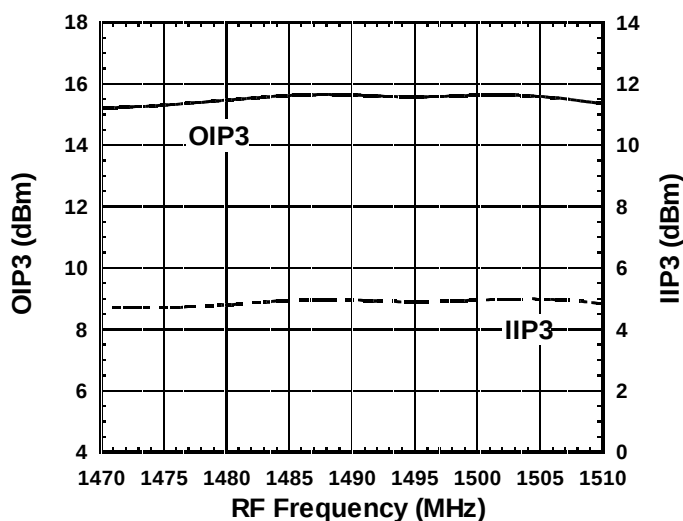
Gc , NF vs. LO Power



Condition

$f_{IF}=130.05\text{MHz}$
 $f_{RF}=1489\text{MHz}$, $P_{RF}=-30\text{dBm}$
 $f_{LO}=1358.95\text{MHz}$
 $V_{MIX}=V_{LO}=V_{INV}=2.8\text{V}$
 $V_{CTL}=2.4\text{V}$

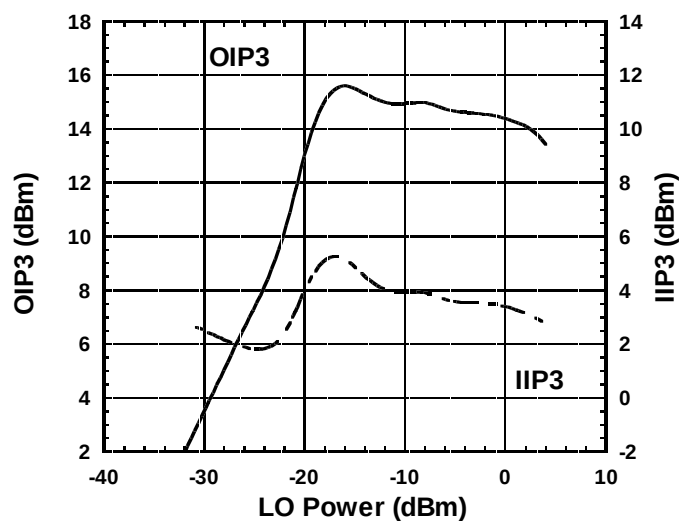
OIP3 , IIP3 vs. RF Frequency



Condition

$f_{IF}=130.05\text{MHz}$
 $f_{RF1}=1470\sim 1510\text{MHz}$
 $f_{RF2}=f_{RF1}+100\text{kHz}$, $P_{RF}=-30\text{dBm}$
 $f_{LO}=1339.95\sim 1379.95\text{MHz}$, $P_{LO}=-15\text{dBm}$
 $V_{MIX}=V_{LO}=V_{INV}=2.8\text{V}$
 $V_{CTL}=2.4\text{V}$

OIP3 , IIP3 vs. LO Power



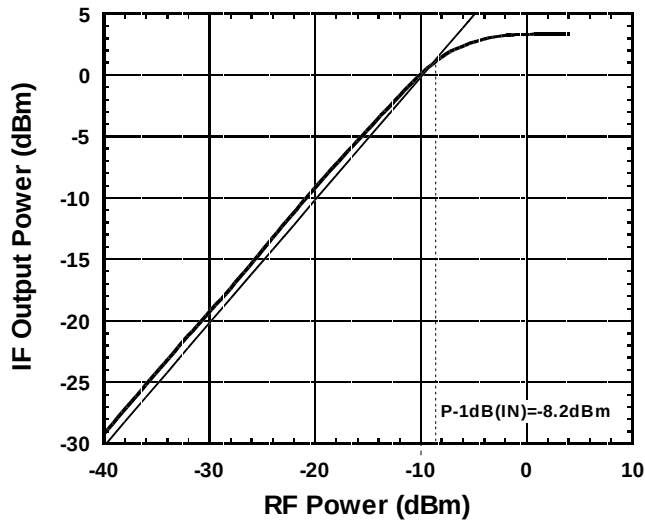
Condition

$f_{IF}=130.05\text{MHz}$
 $f_{RF}=1489.0+1489.1\text{MHz}$, $P_{RF}=-30\text{dBm}$
 $f_{LO}=1358.95\text{MHz}$
 $V_{MIX}=V_{LO}=V_{INV}=2.8\text{V}$
 $V_{CTL}=2.4\text{V}$

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TYPICAL CHARACTERISTICS (1.5GHz Band)

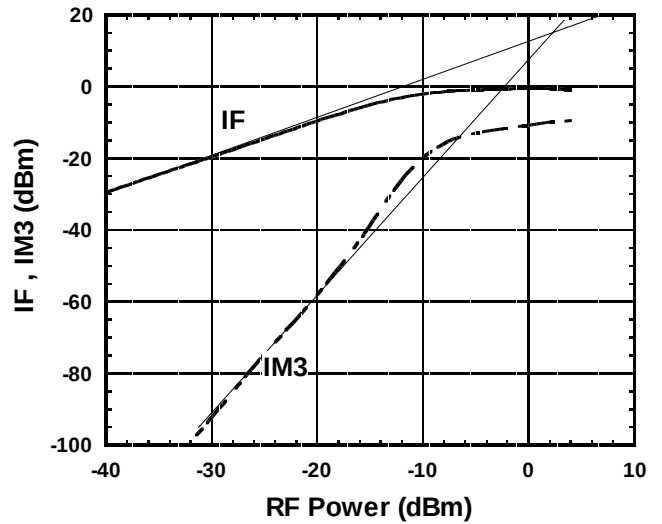
IF Output Power vs. RF Power



Condition

$f_{IF}=130.05\text{MHz}$
 $f_{RF}=1489\text{MHz}$
 $f_{LO}=1358.95\text{MHz}$, $P_{LO}=-15\text{dBm}$
 $V_{MIX}=V_{LO}=V_{INV}=2.8\text{V}$
 $V_{CTL}=2.4\text{V}$

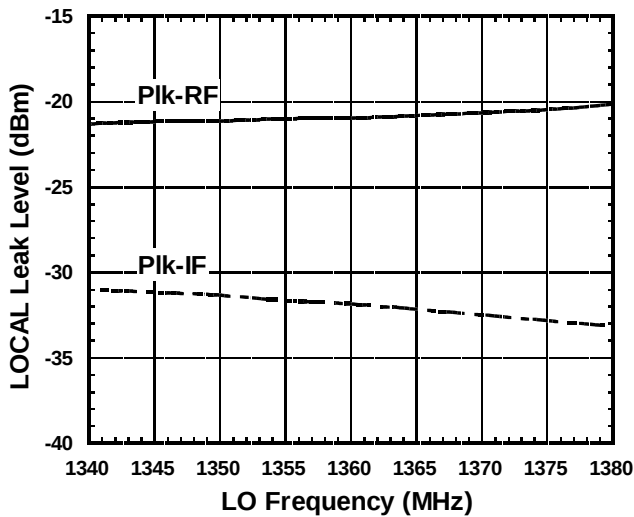
IF , IM3 vs. RF Power



Condition

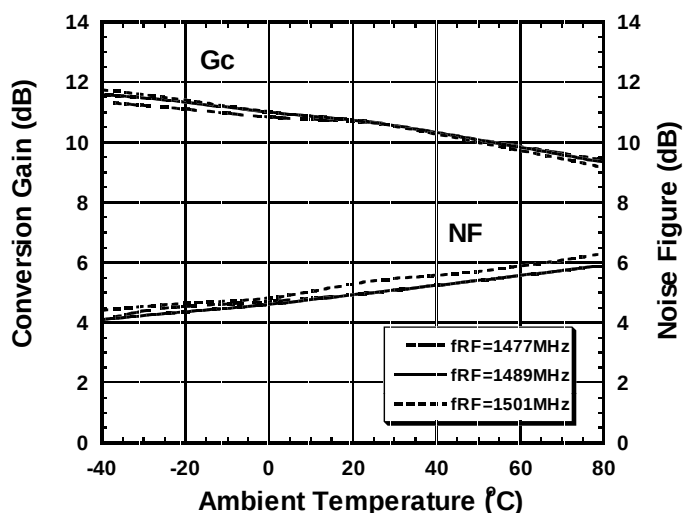
$f_{IF}=130.05\text{MHz}$
 $f_{RF}=1489.0+1489.1\text{MHz}$
 $f_{LO}=1358.95\text{MHz}$, $P_{LO}=-15\text{dBm}$
 $V_{MIX}=V_{LO}=V_{INV}=2.8\text{V}$
 $V_{CTL}=2.4\text{V}$

LOCAL Leak Level vs. LO Frequency

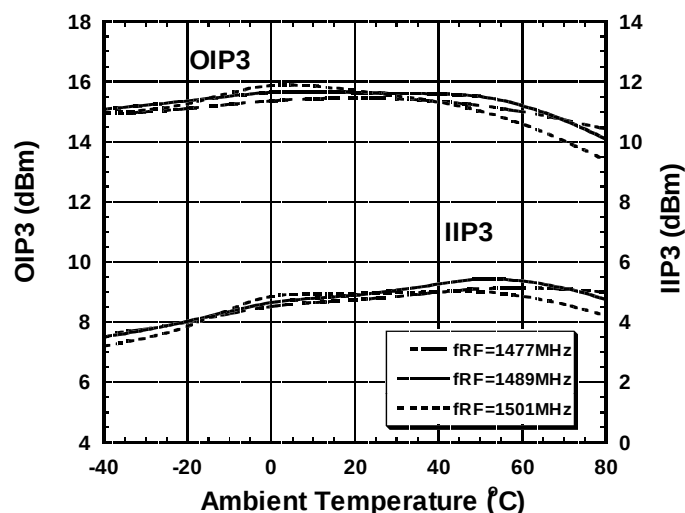


■ TYPICAL CHARACTERISTICS (1.5GHz Band)

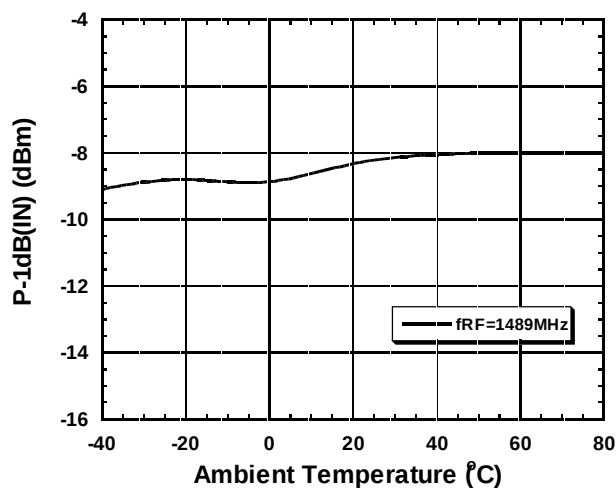
Gc, NF vs. Ambient Temperature



OIP3, IIP3 vs. Ambient Temperature

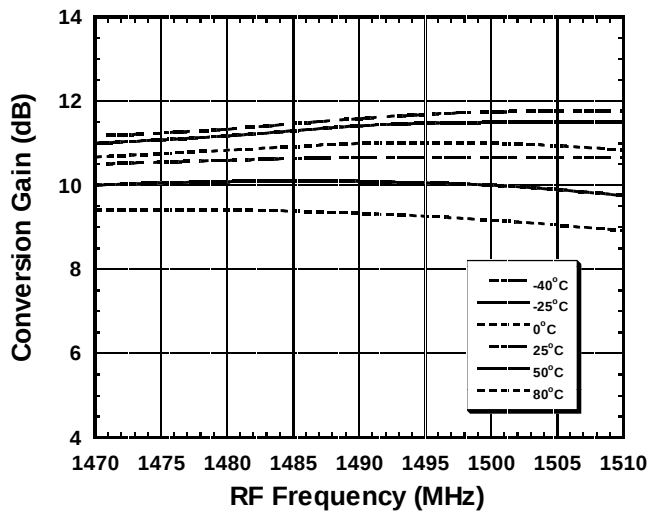


P-1dB(IN) vs. Ambient Temperature

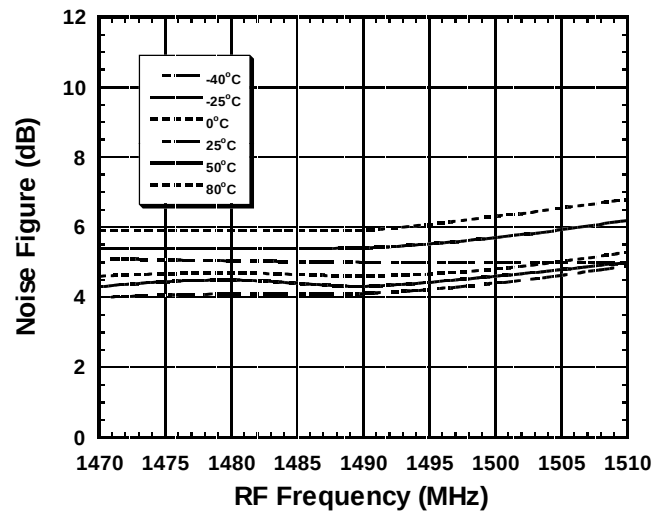


TYPICAL CHARACTERISTICS (1.5GHz Band)

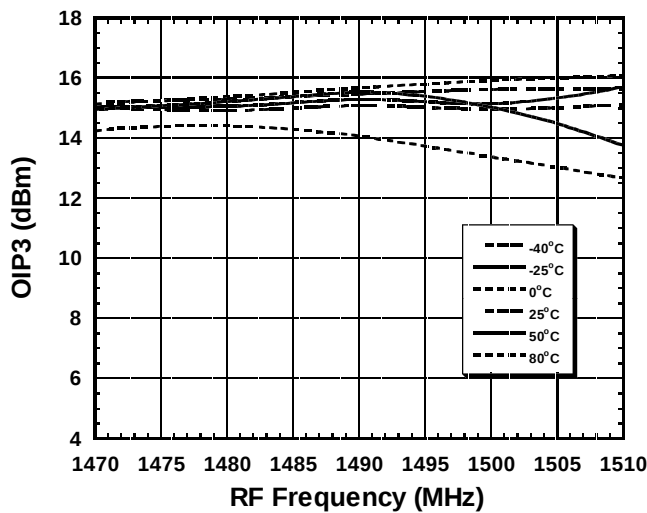
Conversion Gain vs. Frequency



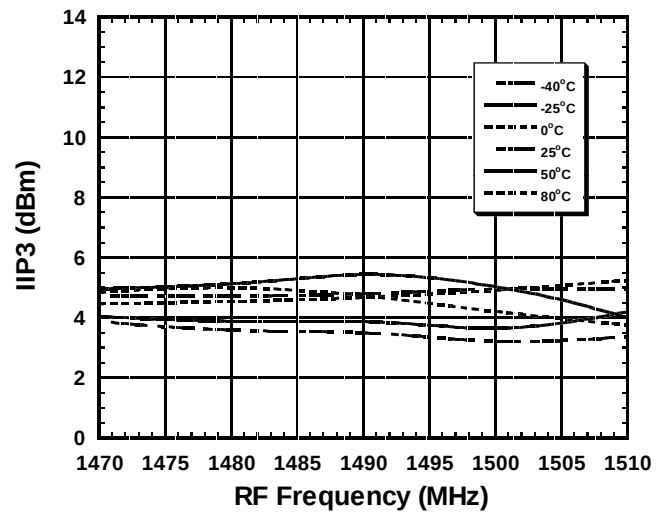
Noise Figure vs. Frequency



OIP3 vs. Frequency

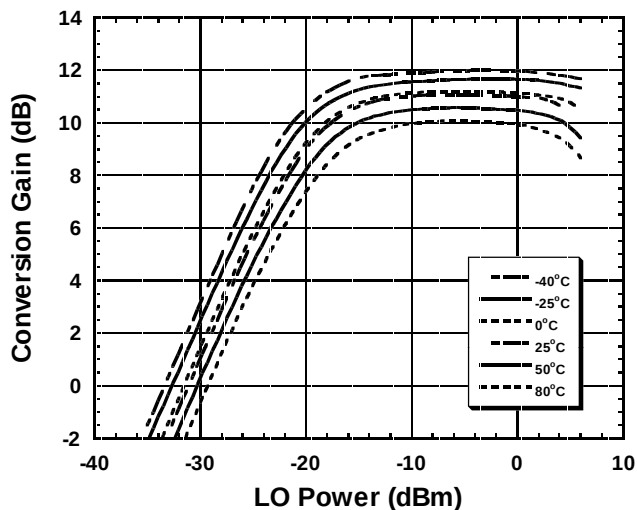


IIP3 vs. Frequency



■ TYPICAL CHARACTERISTICS (1.5GHz Band)

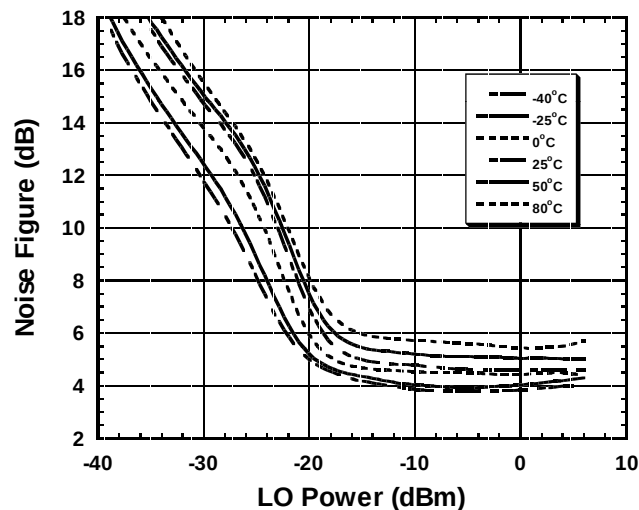
Conversion Gain vs. LO Power



Condition

$f_{IF}=130.05\text{MHz}$
 $f_{RF}=1489\text{MHz}$, $P_{RF}=-30\text{dBm}$
 $f_{LO}=1358.95\text{MHz}$
 $V_{MIX}=V_{LO}=V_{INV}=2.8\text{V}$
 $V_{CTL}=2.4\text{V}$

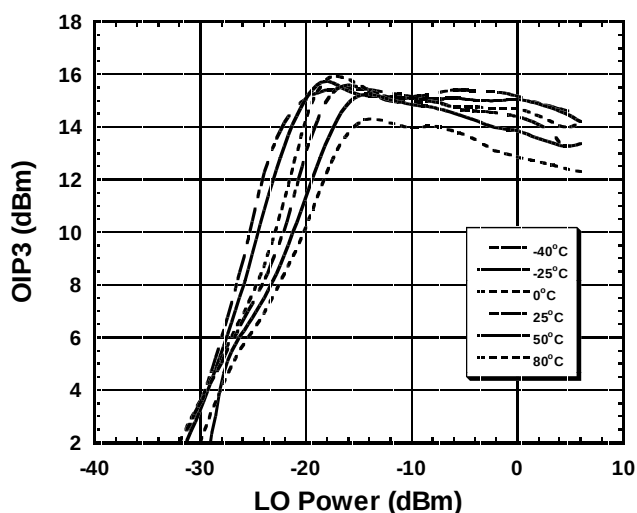
Noise Figure vs. LO Power



Condition

$f_{IF}=130.05\text{MHz}$
 $f_{RF}=1489\text{MHz}$
 $f_{LO}=1358.95\text{MHz}$
 $V_{MIX}=V_{LO}=V_{INV}=2.8\text{V}$
 $V_{CTL}=2.4\text{V}$

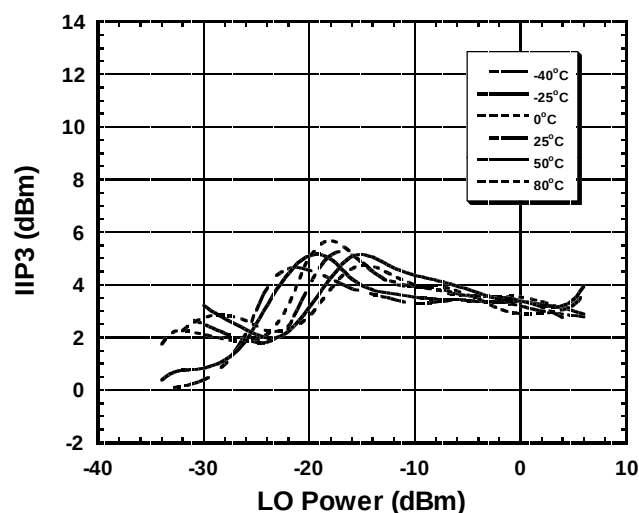
OIP3 vs. LO Power



Condition

$f_{IF}=130.05\text{MHz}$
 $f_{RF}=1489.0+1489.1\text{MHz}$, $P_{RF}=-30\text{dBm}$
 $f_{LO}=1358.95\text{MHz}$
 $V_{MIX}=V_{LO}=V_{INV}=2.8\text{V}$
 $V_{CTL}=2.4\text{V}$

IIP3 vs. LO Power

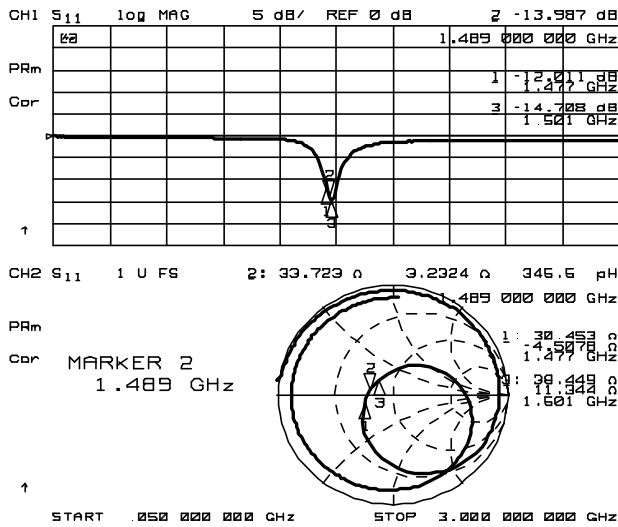


Condition

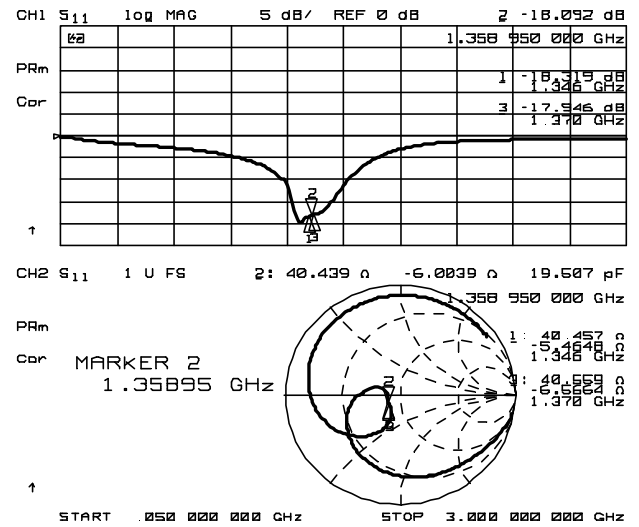
$f_{IF}=130.05\text{MHz}$
 $f_{RF}=1489.0+1489.1\text{MHz}$, $P_{RF}=-30\text{dBm}$
 $f_{LO}=1358.95\text{MHz}$
 $V_{MIX}=V_{LO}=V_{INV}=2.8\text{V}$
 $V_{CTL}=2.4\text{V}$

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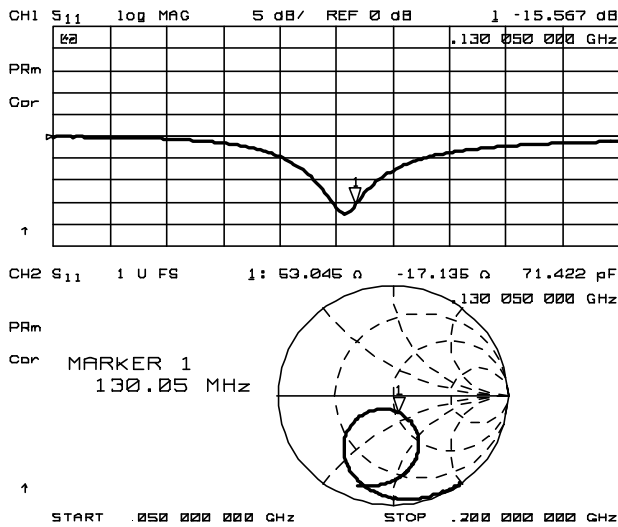
TYPICAL CHARACTERISTICS (1.5GHz Band)



RF IN2 Port Impedance
(LOCAL IN2 Port, IF OUT Port: 50Ω term.)

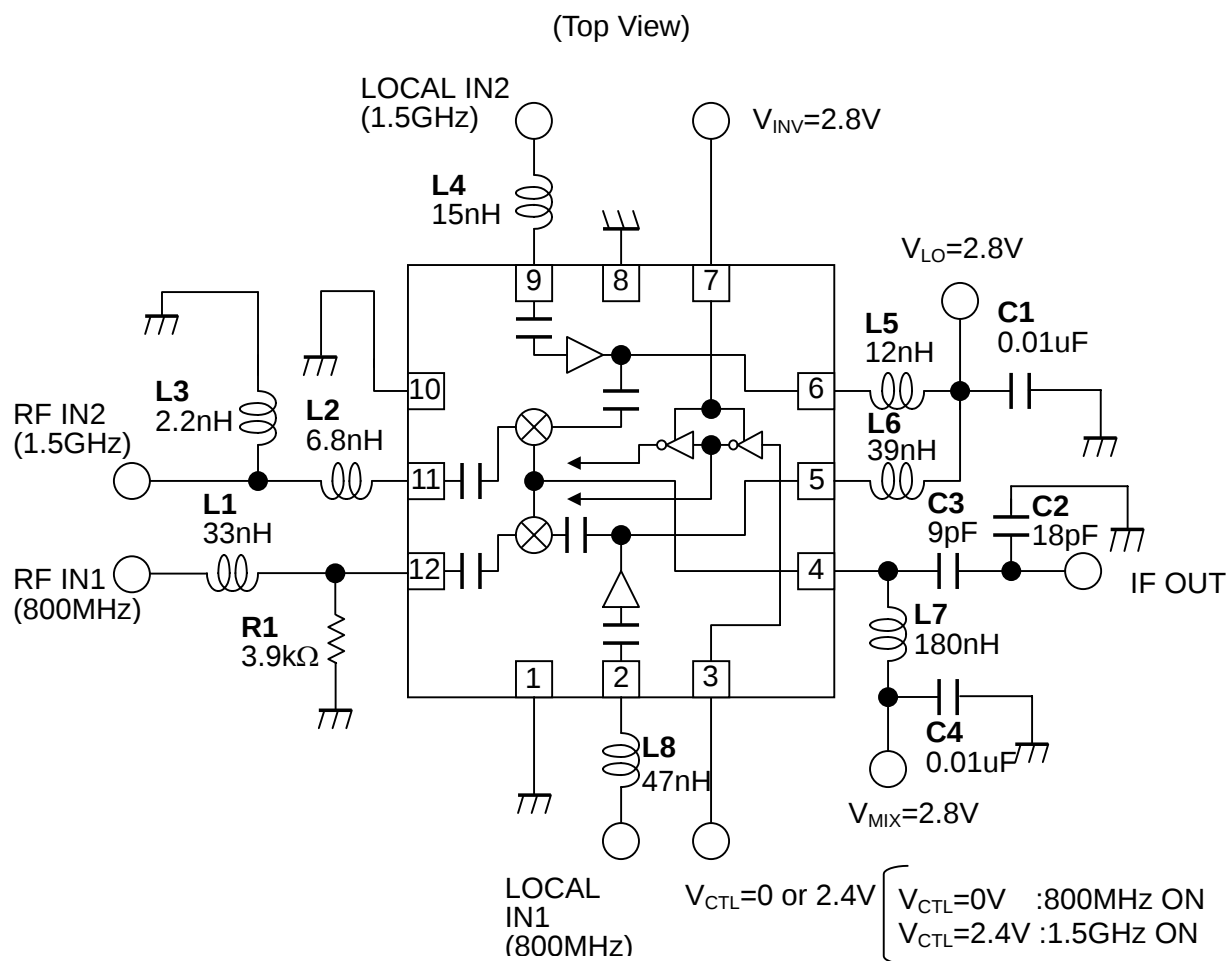


LOCAL IN2 Port Impedance
(RF IN2 Port, IF OUT Port: 50Ω term.)



IF OUT Port Impedance
(RF IN2 Port, LOCAL IN2 Port: 50Ω term.)

APPLICATION CIRCUIT

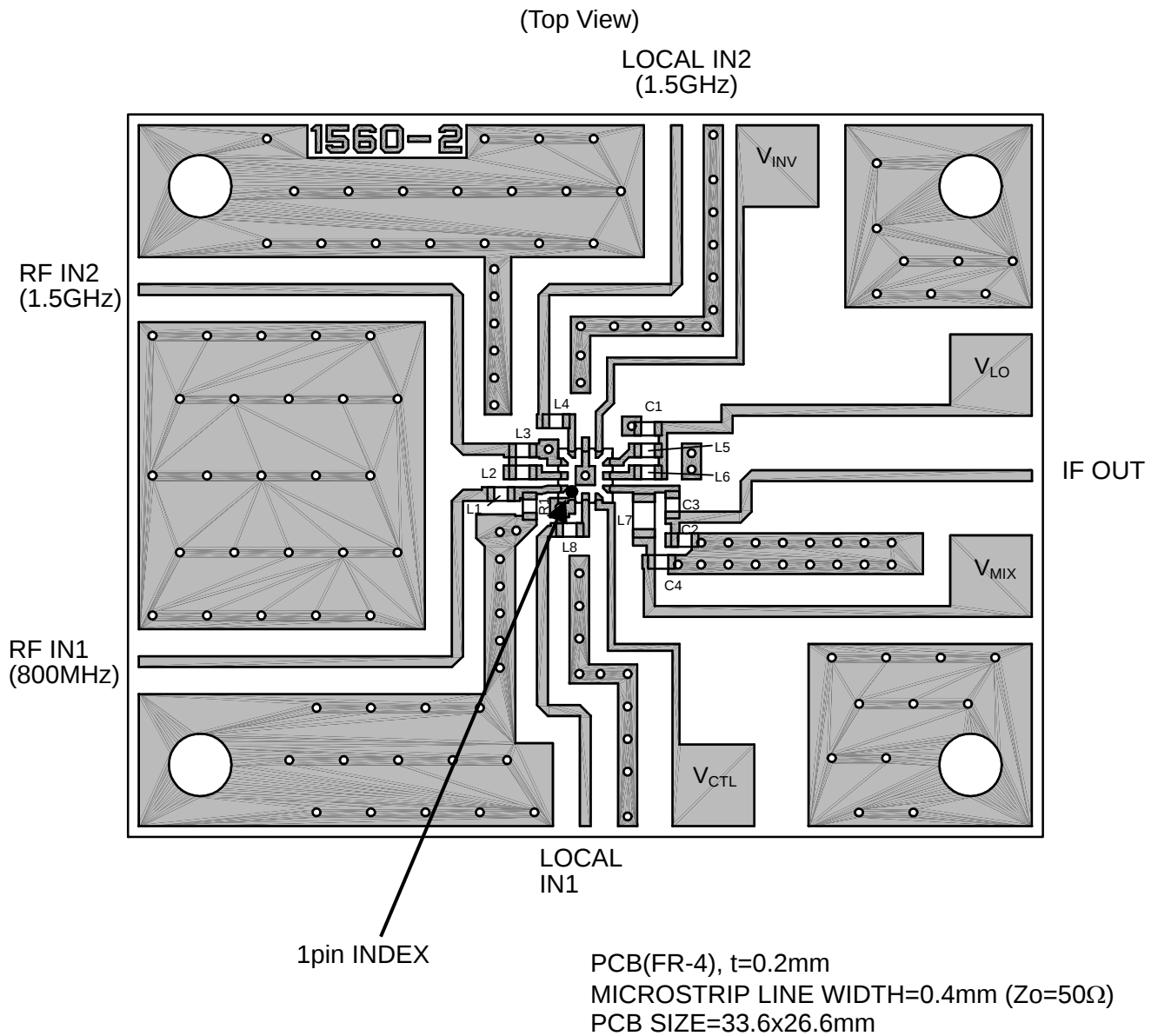


Parts list

PARTS ID	COMMENT
L1	TAIYO-YUDEN (HK1005, 1005size)
L2	TAIYO-YUDEN (HK1005, 1005size)
L3	TAIYO-YUDEN (HK1005, 1005size)
L4	TAIYO-YUDEN (HK1005, 1005size)
L5	TAIYO-YUDEN (HK1005, 1005size)
L6	TAIYO-YUDEN (HK1005, 1005size)
L7	TAIYO-YUDEN (HK1608, 1608size)
L8	TAIYO-YUDEN (HK1005, 1005size)
C1	MURATA (GRM36, 1005size)
C2	MURATA (GRM36, 1005size)
C3	MURATA (GRM36, 1005size)
C4	MURATA (GRM36, 1005size)
R1	1005 Size

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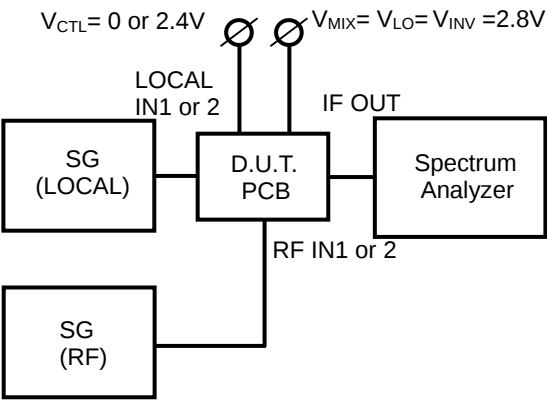
RECOMMENDED PCB DESIGN



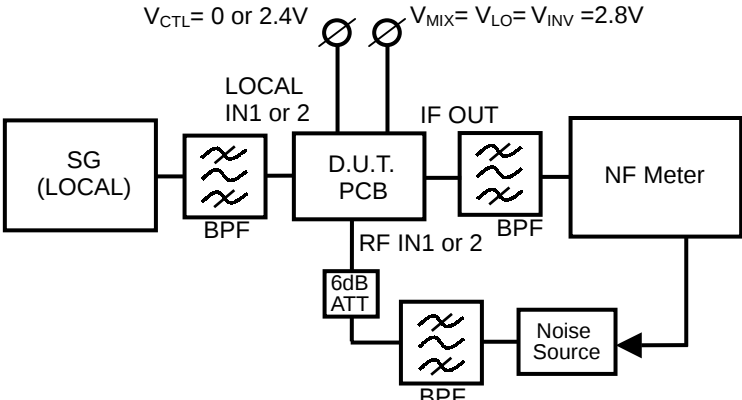
PRECAUTIONS

1. Please locate L6 close to VLO1 terminal (5).
2. Please locate L5 close to VLO2 terminal (6).
3. Please locate C1 close to L5 and L6.
4. Please locate C4 close to L7.

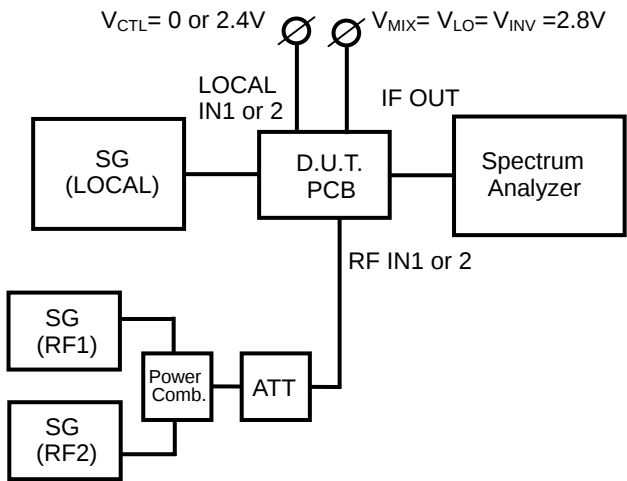
MEASURING BLOCK DIAGRAM



Conversion Gain Measuring Block Diagram



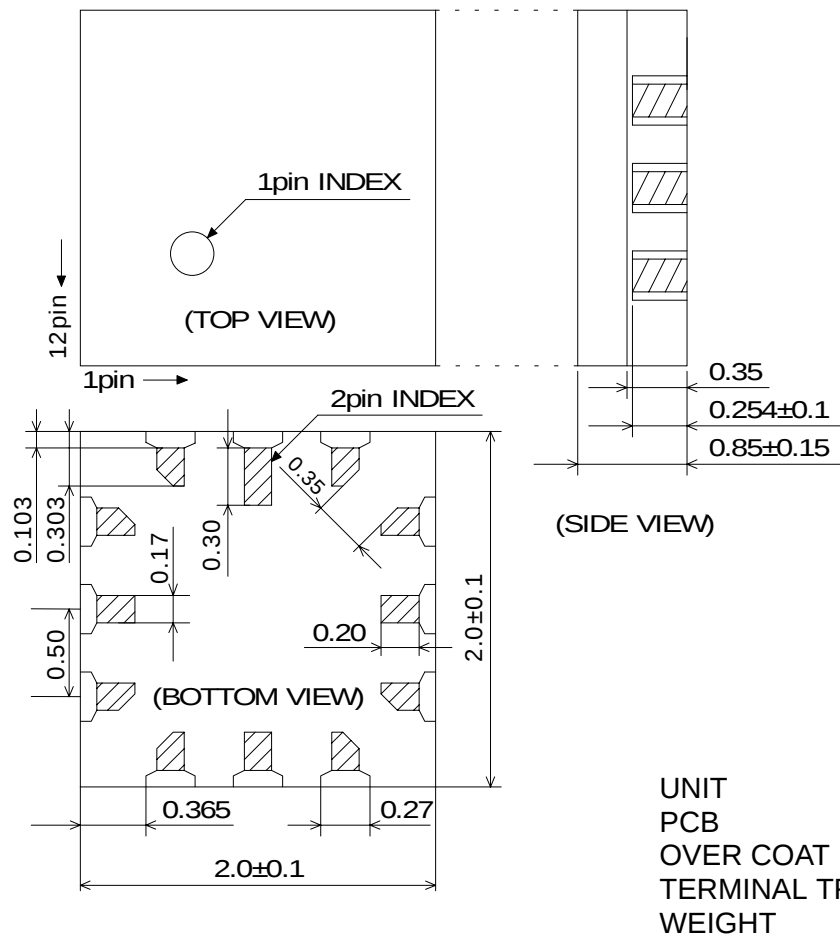
Noise Figure Measuring Block Diagram



OIP3, IIP3 Measuring Block Diagram

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■PACKAGE OUTLINE (FFP12-B1)



Cautions on using this product

This product contains Gallium-Arsenide (GaAs) which is a harmful material.

- Do NOT eat or put into mouth.
- Do NOT dispose in fire or break up this product.
- Do NOT chemically make gas or powder with this product.
- To waste this product, please obey the relating law of your country.

[CAUTION]

The specifications on this databook are only given for information, without any guarantee as regards either mistakes or omissions. The application circuits in this databook are described only to show representative usages of the product and not intended for the guarantee or permission of any right including the industrial rights.

This product may be damaged with electric static discharge (ESD) or spike voltage. Please handle with care to avoid these damages.